

# **Lattice Avant Embedded Memory User Guide**

# **Preliminary** Technical Note



#### **Disclaimers**

Lattice makes no warranty, representation, or guarantee regarding the accuracy of information contained in this document or the suitability of its products for any particular purpose. All information herein is provided AS IS, with all faults, and all associated risk is the responsibility entirely of the Buyer. The information provided herein is for informational purposes only and may contain technical inaccuracies or omissions, and may be otherwise rendered inaccurate for many reasons, and Lattice assumes no obligation to update or otherwise correct or revise this information. Products sold by Lattice have been subject to limited testing and it is the Buyer's responsibility to independently determine the suitability of any products and to test and verify the same. LATTICE PRODUCTS AND SERVICES ARE NOT DESIGNED, MANUFACTURED, OR TESTED FOR USE IN LIFE OR SAFETY CRITICAL SYSTEMS, HAZARDOUS ENVIRONMENTS, OR ANY OTHER ENVIRONMENTS REQUIRING FAIL-SAFE PERFORMANCE, INCLUDING ANY APPLICATION IN WHICH THE FAILURE OF THE PRODUCT OR SERVICE COULD LEAD TO DEATH, PERSONAL INJURY, SEVERE PROPERTY DAMAGE OR ENVIRONMENTAL HARM (COLLECTIVELY, "HIGH-RISK USES"). FURTHER, BUYER MUST TAKE PRUDENT STEPS TO PROTECT AGAINST PRODUCT AND SERVICE FAILURES, INCLUDING PROVIDING APPROPRIATE REDUNDANCIES, FAIL-SAFE FEATURES, AND/OR SHUT-DOWN MECHANISMS. LATTICE EXPRESSLY DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY OF FITNESS OF THE PRODUCTS OR SERVICES FOR HIGH-RISK USES. The information provided in this document is proprietary to Lattice Semiconductor, and Lattice reserves the right to make any changes to the information in this document or to any products at any time without notice.

#### **Inclusive Language**

This document was created consistent with Lattice Semiconductor's inclusive language policy. In some cases, the language in underlying tools and other items may not yet have been updated. Please refer to Lattice's inclusive language FAQ 6878 for a cross reference of terms. Note in some cases such as register names and state names it has been necessary to continue to utilize older terminology for compatibility.



### **Contents**

Acronyms in This Document	6
1. Introduction	7
2. Memory Generation	8
2.1. IP Catalog Flow	8
2.2. Utilizing PMI	10
2.3. Utilizing Direct Instantiation of Memory Primitives	10
3. Memory Features	11
3.1. ECC in Memory Modules	11
3.2. Byte Enable	11
4. Memory Modules	12
4.1. Memory Cascading	
4.1.1. Input and Output Register	12
4.1.2. Reset	12
4.1.3. Timing	
4.2. Single Port RAM (RAM_DQ) – EBR-Based	
4.3. True Dual-Port RAM (RAM_DP_TRUE) – EBR-Based	
4.4. Pseudo Dual-Port RAM (RAM_DP) – EBR-Based	
4.5. Read Only Memory (ROM) – EBR-Based	
5. First In First Out (FIFO) Memory	
5.1. Single-Clock FIFO (FIFO) – EBR-Based or LUT-Based	
6. Dual-Clock First-In-First-Out (FIFO_DC) – EBR-Based or LUT-Based	
6.1. FIFO_DC Flags	
7. Distributed Single-Port RAM (Distributed_SPRAM) – PFU-Based	
8. Distributed Dual-Port RAM (Distributed_DPRAM) – PFU-Based	
9. Distributed ROM (Distributed_ROM) – PFU-Based	
10. Initializing Memory	
10.1. Initialization File Formats	
10.1.1. Binary File	
10.1.2. Hex File	
References	
Technical Support Assistance	
Revision History	57



# **Figures**

Figure 2.1. Memory Modules Available in IP Catalog	8
Figure 2.2. IP Catalog in the Lattice Radiant Software	
Figure 2.3. Example: Generating Pseudo Dual Port RAM (RAM_DP) Using IP Catalog	
Figure 2.4. Example: Generating Pseudo Dual Port RAM (RAM_DP) Module Customization – General Options	
Figure 4.1. Single-Port Memory Module Generated by IP Catalog	
Figure 4.2. Single Port RAM Primitive for Lattice Avant Platform Devices	
Figure 4.3. Single Port RAM Timing Waveform – without Output Registers	
Figure 4.4. Single Port RAM Timing Waveform – with Output Registers	
Figure 4.5. True Dual-Port Memory Module Generated by IP Catalog	
Figure 4.6. True Dual Port RAM Primitive for Lattice Avant Platform Devices	
Figure 4.7. True Dual Port RAM Timing Waveform – without Output Registers	
Figure 4.8. True Dual Port RAM Timing Waveform – with Output Registers	
Figure 4.9. Pseudo Dual-Port Memory Module Generated by IP Catalog	
Figure 4.10. Pseudo-Dual Port RAM Primitive for Lattice Avant Platform Devices	
Figure 4.11. PSEUDO DUAL PORT RAM Timing Diagram – without Output Registers	
Figure 4.12. PSEUDO DUAL PORT RAM Timing Diagram – with Output Registers	
Figure 4.13. ROM – Read Only Memory Module Generated by IP Catalog	
Figure 4.14. ROM Timing Waveform – without Output Registers	
Figure 4.15. ROM Timing Waveform – with Output Registers	
Figure 5.1. FIFO Module Generated by IP Catalog	
Figure 5.2. FIFO Without Output Registers – Start of Data Write Cycle	
Figure 5.3. FIFO Without Output Registers – End of Data Write Cycle	
Figure 5.4. FIFO Without Output Registers – Start of Data Read Cycle	
Figure 5.5. FIFO Without Output Registers – End of Data Read Cycle	
Figure 5.6. FIFO with Output Registers – Start of Data Write Cycle	
Figure 5.7. FIFO with Output Registers – End of Data Write Cycle	
Figure 5.8. FIFO with Output Registers – Start of Data Read Cycle	
Figure 5.9. FIFO with Output Registers – End of Data Read Cycle	32
Figure 5.10. FIFO with Output Registers and RdEn on Output Registers	33
Figure 6.1. FIFO_DC Module Generated by IP Catalog	34
Figure 6.2. FIFO_DC Without Output Registers – Start of Data Write Cycle	
Figure 6.3. FIFO_DC Without Output Registers – End of Data Write Cycle	37
Figure 6.4. FIFO_DC Without Output Registers – Start of Data Read Cycle	38
Figure 6.5. FIFO_DC Without Output Registers – End of Data Read Cycle	39
Figure 6.6. FIFO_DC with Output Registers – Start of Data Write Cycle	40
Figure 6.7. FIFO_DC with Output Registers – End of Data Write Cycle	41
Figure 6.8. FIFO_DC with Output Registers – Start of Data Read Cycle	42
Figure 6.9. FIFO_DC with Output Registers – End of Data Read Cycle	43
Figure 6.10. FIFO_DC with Output Registers and RdEn on Output Registers	44
Figure 7.1. Distributed Single-Port RAM Module Generated by IP Catalog	45
Figure 7.2. Single Port Distributed RAM Primitive for Lattice Avant Platform Devices	45
Figure 7.3. PFU-Based Distributed Single Port RAM Timing Waveform – without Output Registers	46
Figure 7.4. PFU-Based Distributed Single Port RAM Timing Waveform – with Output Registers	47
Figure 8.1. Distributed Dual-Port RAM Module Generated by IP Catalog	48
Figure 8.2. Dual Port Distributed RAM Primitive for Lattice Avant Platform Devices	48
Figure 8.3. PFU-Based Distributed Dual Port RAM Timing Waveform – without Output Registers	50
Figure 8.4. PFU-Based Distributed Dual Port RAM Timing Waveform – with Output Registers	
Figure 9.1. Distributed ROM Generated by IP Catalog	
Figure 9.2. PFU-Based Distributed Dual Port RAM Timing Waveform – without Output Registers	52
Figure 9.3. PFU-Based Distributed Dual Port RAM Timing Waveform – with Output Registers	52



### **Tables**

Table 4.1. EBR-Based Single-Port Memory Port Definitions 1	Table 3.1. Masked Data in Bits for a 9-Bit Byte Size	11
Table 4.3. Single-Port Memory Attributes in Lattice Avant Platform Devices1Table 4.4. EBR-Based True Dual-Port Memory Port Definitions1Table 4.5. Dual Port Memory Sizes for 36 kb Memory for Avant Platform Devices1Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices1Table 4.7. EBR-Based True Dual-Port Memory Port Definitions2Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 8.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5		
Table 4.4. EBR-Based True Dual-Port Memory Port Definitions1Table 4.5. Dual Port Memory Sizes for 36 kb Memory for Avant Platform Devices1Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices1Table 4.7. EBR-Based True Dual-Port Memory Port Definitions2Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.2. Single-Port Memory Sizes for 36 kb Memory in Lattice Avant Platform Devices	14
Table 4.5. Dual Port Memory Sizes for 36 kb Memory for Avant Platform Devices1Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices1Table 4.7. EBR-Based True Dual-Port Memory Port Definitions2Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.3. Single-Port Memory Attributes in Lattice Avant Platform Devices	14
Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices1Table 4.7. EBR-Based True Dual-Port Memory Port Definitions2Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.4. EBR-Based True Dual-Port Memory Port Definitions	17
Table 4.7. EBR-Based True Dual-Port Memory Port Definitions2Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.5. Dual Port Memory Sizes for 36 kb Memory for Avant Platform Devices	17
Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices	17
Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices2Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.7. EBR-Based True Dual-Port Memory Port Definitions	21
Table 4.10. EBR-Based ROM Port Definitions2Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices	21
Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices2Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices	21
Table 4.12. ROM Attributes for Lattice Avant Platform Devices2Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.10. EBR-Based ROM Port Definitions	24
Table 5.1. Port Names and Definitions for FIFO2Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices	24
Table 5.2. FIFO Attributes for Lattice Avant Platform Devices2Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 4.12. ROM Attributes for Lattice Avant Platform Devices	24
Table 6.1. Port Names and Definitions for FIFO_DC3Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices3Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions4Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices4Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions4Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices4Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 5.1. Port Names and Definitions for FIFO	26
Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices	Table 5.2. FIFO Attributes for Lattice Avant Platform Devices	27
Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions	Table 6.1. Port Names and Definitions for FIFO_DC	34
Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices       4         Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions       4         Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices       4         Table 9.1. PFU-Based Distributed ROM Port Definitions       5	Table 6.2. FIFO_DC Attributes for Lattice Avant Platform Devices	35
Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions	Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions	46
Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices	Table 7.2. Distributed_SPRAM Attributes for Lattice Avant Platform Devices	46
Table 9.1. PFU-Based Distributed ROM Port Definitions5	Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions	49
	Table 8.2. Distributed_DPRAM Attributes for Lattice Avant Platform Devices	49
Table 9.2. Distributed_ROM Attributes for Lattice Avant Platform Devices5	Table 9.1. PFU-Based Distributed ROM Port Definitions	51
	Table 9.2. Distributed_ROM Attributes for Lattice Avant Platform Devices	51



# **Acronyms in This Document**

A list of acronyms used in this document.

Acronym	Definition
AW	Address Width
DW	Data Width
ECC	Error Correction Code
EBR	Embedded Block RAM
FIFO	First In First Out
GSR	Global Set/Reset
IP	Intellectual Property
LUT	Look Up Table
LSB	Least Significant Bit
PFU	Programmable Function Unit
PMI	Parameterizable Module Instantiation
RAM	Random Access Memory
ROM	Read Only Memory
SECDED	Single Error Correction-Double Error Detection
SRAM	Static Random Access Memory
VHDL	VHSIC Hardware Description Language



### 1. Introduction

This technical note discusses memory usage for the Lattice Semiconductor devices built on the Lattice Avant™ platform. It is intended to be used by design engineers as a guide when integrating the Embedded Block RAM (EBR)-based and Programmable Function Unit(PFU)-based memories for these device families in the Lattice Radiant™ software.

The architecture of these devices provides many resources for memory-intensive applications. The sysMEM™ EBR complements its distributed PFU-based memory. Single-Port RAM, Dual-Port RAM, Pseudo Dual-Port RAM, FIFO, and ROM memories can be constructed using the EBR. The look-up tables (LUTs) and PFUs can implement Distributed Single-Port RAM, Dual-Port RAM, and ROM. LUTs within PFUs can implement Distributed Single-Port RAM, Dual-Port RAM, and ROM.

The capabilities of the EBR Block RAM and PFU RAM are described in this document. You can utilize the memory primitives in three separate ways:

- Through the IP Catalog The IP Catalog interface allows you to specify the memory type and size required. The IP
  Catalog takes this specification and constructs a netlist to implement the desired memory by using one or more of the
  memory primitives.
- Through Parameterizable Module Inferencing (PMI) PMI allows you to skip the graphical interface and utilize the configurable memory primitives on-the-fly from the Lattice Radiant project navigator. You can set the parameters and the control signals needed either in Verilog or VHDL. The top-level design has the parameters defined and signals declared so the interface can automatically generate the black box during synthesis.
- Through the Instantiation of Memory Primitives Memory primitives are called directly by the top-level module and
  instantiated in the design. This is an advanced method and requires a thorough understanding of memory hook-ups
  and design interfaces.

The remainder of this document discusses these methods.



### 2. Memory Generation

You can use the IP Catalog to easily specify a variety of memories in the designs. These modules are constructed using one or more memory primitives along with general-purpose routing and LUTs as required.

The available modules in the IP Catalog are as follows:

- Distributed Memory Modules
  - Distributed Pseudo Dual Port RAM (Distributed\_DPRAM)
  - Distributed ROM (Distributed ROM)
  - Distributed Single Port RAM (Distributed SPRAM)
- EBR Components (or EBR-based Modules)
  - Dual PORT RAM (RAM DP TRUE)
  - Pseudo Dual Port RAM (RAM\_DP)
  - Single Port RAM (RAM\_DQ)
  - Read Only Memory (ROM)
- First In First Out Memory (EBR or LUT)
  - FIFO Single Clock (FIFO)
  - FIFO Dual Clock (FIFO\_DC)

Figure 2.1 shows the memory modules under IP Catalog in the Lattice Radiant software.

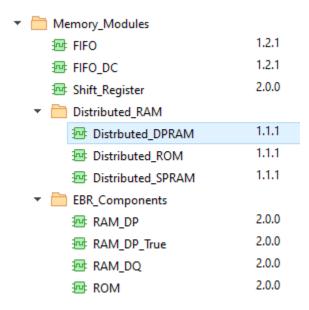


Figure 2.1. Memory Modules Available in IP Catalog

### 2.1. IP Catalog Flow

The IP Catalog allows you to generate, create, or open any of the available modules for Lattice Avant platform devices. In the Lattice Radiant software, choose **View > Show Views > IP Catalog**, or click the IP Catalog icon in the toolbar. This opens the IP Catalog window, as shown in Figure 2.2.



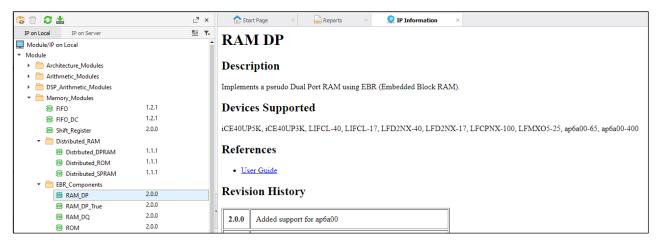


Figure 2.2. IP Catalog in the Lattice Radiant Software

The left section of the IP Catalog window includes the Module Tree. The Memory Modules are categorized as Distributed RAM, EBR Components, FIFOs, and Shift Register. The right section of the window shows the description of the module selected and links to the documentation for additional information.

This section provides an example of generating an EBR-based Pseudo Dual Port RAM of size 512 x 36.

To generate an EBR-based Pseudo Dual Port RAM:

- Double-click ram\_dp under the EBR\_Components.
- 2. Fill out the module information, as shown in Figure 2.3.
- 3. Click the Next button.

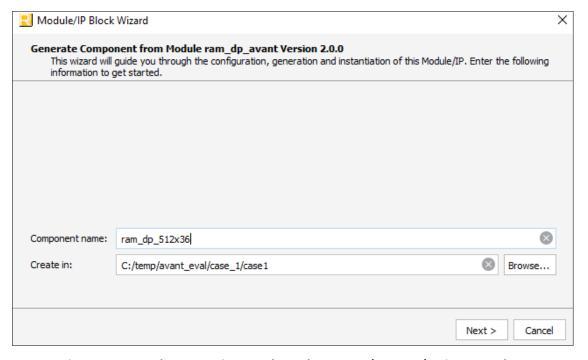


Figure 2.3. Example: Generating Pseudo Dual Port RAM (RAM\_DP) Using IP Catalog





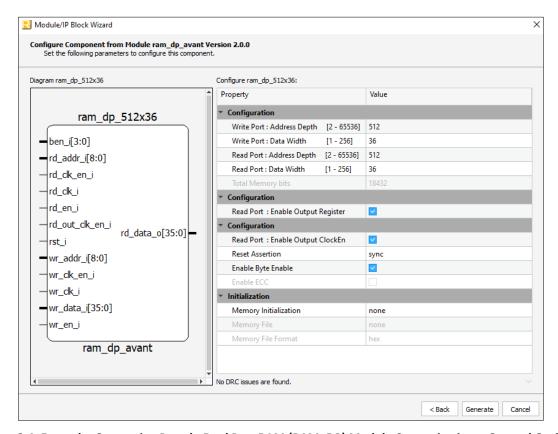


Figure 2.4. Example: Generating Pseudo Dual Port RAM (RAM\_DP) Module Customization – General Options

5. When all the options of the module being generated are filled out, click **Generate**. Once this module is in the Lattice Radiant project, it can be instantiated within other modules.

### 2.2. Utilizing PMI

You can set the parameters and control signals needed in either Verilog or VHDL. The top-level design includes the defined memory parameters and declared signals. The interface can then automatically generate the black box during synthesis and Lattice Radiant can generate the netlist on-the-fly. Lattice memories are the same as industry standard memories, so you can get the parameters for each module from any memory-related guide, which is available through the Online Help system.

To do this, create a Verilog or VHDL behavior code for the memory and the synthesis tool automatically identifies it as memory and synthesizes it as a distributed or EBR memory. In general, memory sizes smaller than 1 kb are automatically mapped to Distributed mode and those larger than 1 kb are implemented using EBRs. This default option can be over-ridden using the syn\_ramstyle or syn\_romstyle attribute in Synopsys Synplify Pro®.

### 2.3. Utilizing Direct Instantiation of Memory Primitives

Another way to use the memories in the designs is by directly instantiating the memory primitives for the Avant platform devices. When instantiating the primitives, you must work at the EBR block level. In case there is a need to have a memory that spans multiple modules, you are required to create the cascading memory on its own.

Lattice provides library files containing all of the primitives in a VHDL/Verilog file under the cae\_library/synthesis folder in the Lattice Radiant software installation folder.

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice



## 3. Memory Features

The RAMs can be generated with error correction and byte enable features that mask selective bits. These features are available in the EBR-based RAM modules.

### 3.1. ECC in Memory Modules

An error-correction code (ECC) is a system of adding redundant data, or parity data, to a message, such that it can be recovered by a receiver even when a number of errors are introduced, either during the process of transmission, or on storage.

EBR-based memory modules IP Catalog allows you to implement ECC. There is a check box to enable ECC in the Configuration tab for the module.

Enable ECC check box allows error correction of single errors and detection of 2-bit errors. ECC write is supported only in x64 write mode with 8-bit ECC. ECC read may be performed in x1, x2, x4, x8, x16, x32, or x64 modes.

The two bits indicate the error if any, and the following shows you what each of these bits mean:

- one err det o = 1 Indicates there is a 1-bit error that is fixed.
- two\_err\_det\_o = 1 Indicates there is a 2-bit error that cannot be corrected.

The error flags are aligned to the output data and are available in the same cycle as the respective data.

### 3.2. Byte Enable

Byte enable is a feature available in selected RAM modules where you can mask the bytes written in the RAM. The byte enable feature is available only when the data width is greater than nine bits. Each byte enable bit controls the write data operation enable for the nine bits. The selection can be made in IP Catalog while generating the module.

Each bit of the BE signal corresponds to the corresponding 9-bit selection, starting from LSB side. For example, if you add byte enable to a 72-bit wide RAM, then Table 3.1 explains how the written data (Data In) is masked for a 9-bit byte size. Bits 8, 17, 26, 35, 44, 53, 62, and 71 are parity bits, which you ignore in x8, x16, x32, and x64 modes.

Table 3.1. Masked Data in Bits for a 9-Bit Byte Size

Byte Enable Bit	Data In Bits that Get Masked (with 9-bit Byte Size)
ByteEn(0)	Data(8:0)
ByteEn(1)	Data(17:9)
ByteEn(2)	Data(26:18)
ByteEn(3)	Data(35:27)
ByteEn(4)	Data(44:36)
ByteEn(5)	Data(53:45)
ByteEn(6)	Data(62:54)
ByteEn(7)	Data(71:63)

Note that the ByteEn and ECC are mutually exclusive and they cannot be used together.

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



## 4. Memory Modules

The following sections discuss the different modules, the size of memory that each EBR block or the Distributed primitive can support, and any special options for the module.

When you specify the width and depth of the memory in the IP Catalog, the tool generates the memory by depth cascading and/or width cascading or EBR blocks or Distributed RAM primitives. IP Catalog automatically allows you to create memories larger than the width and depth supported for each primitive.

### 4.1. Memory Cascading

For memory sizes that are smaller than what can fit in a single EBR block or the Distributed primitive, the module utilizes the complete block or primitive.

For memory sizes larger than that of a single module, multiple modules are cascaded either in depth or width to create a larger module.

#### 4.1.1. Input and Output Register

The architecture of the EBR blocks in Avant platform devices are designed such that the inputs that go into the memory are always registered. This means that the input data and address are always registered at the input of the memory array. The output data of the memory is optionally registered at the output. You can choose this option by selecting the Enable Output Register check box in IP Catalog while customizing the module.

Control signals like WE and Byte Enable that go into the EBR block are also registered.

#### 4.1.2. Reset

The EBRs also support the Reset signal. The Reset (or RST) signal only resets input and output registers of the RAM. It does not reset the contents of the memory. The global set/reset (GSR) signal also controls the output registers.

#### 4.1.3. Timing

To correctly write to a memory cell in the EBR block, the correct address must be registered by the logic. Hence, it is important to note that while running the trace on the EBR blocks, there should be no setup and hold time violations on the address registers (address). Failing to meet these requirements can result in incorrect addressing and hence, lead to the corruption of memory contents.

During a read cycle, a similar issue can occur such that the correct contents are not read if the address is not correctly registered in the memory.

A Post-Place and Route timing report in the Lattice Radiant design software can be run to verify that no such timing errors occur. For more information, refer to the timing preferences in the Online Help documents.



13

### 4.2. Single Port RAM (RAM\_DQ) – EBR-Based

FPGAs built on the Avant platform support all the features of Single Port Memory Module or RAM\_DQ. IP Catalog allows you to generate the Verilog-HDL or VHDL for the memory size as per design requirement.

IP Catalog generates the memory module, as shown in Figure 4.1.

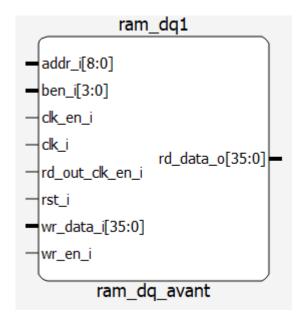


Figure 4.1. Single-Port Memory Module Generated by IP Catalog

Figure 4.2 shows the primitive that can be instantiated for the Single Port RAM. The primitive name is SP32K and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under cae\_library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 36 kb of memory. If the memory required is larger than 36 kb, then cascading can be used, using the CS port (CS[2:0] in this case).

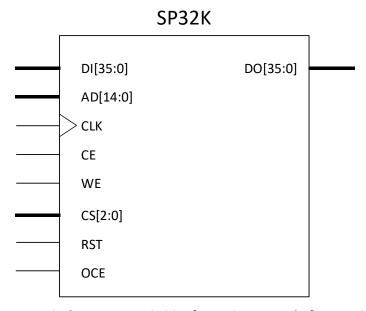


Figure 4.2. Single Port RAM Primitive for Lattice Avant Platform Devices

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice. FPGA-TN-02289-0.82



The various ports and definitions for Single-Port Memory are listed in Table 4.1. The table below lists the corresponding ports for the module generated by IP Catalog.

Table 4.1. EBR-Based Single-Port Memory Port Definitions<sup>1</sup>

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	(Input) Clock Enable
rd_out_clk_en_i	Input	1	Read Output Register Enable (Present if Enable Output Register == TRUE)
wr_en_i	Input	1	Write Enable
wr_data_i	Input	Data Width	Data Input
addr_i	Input	Address Width	Address Bus
rd_data_o	Output	Data Width	Data Output
ben_i	Input	Byte Enable Width	Byte Enable

#### Note:

Each EBR block consists of 36,864 bits of RAM. The values for x (address) and y (data) of each EBR block are listed in Table 4.2.

Table 4.2. Single-Port Memory Sizes for 36 kb Memory in Lattice Avant Platform Devices

Single Port Memory Size	Input Data	Output Data	Address [MSB:LSB]
32,768 × 1	DI	DO	AD[14:0]
16,384 × 2	DI[1:0]	DO[1:0]	AD[13:0]
8,192 × 4	DI[3:0]	DO[3:0]	AD[13:0]
4,096 × 9	DI[8:0]	DO[8:0]	AD[11:0]
2,048 × 18	DI[17:0]	DO[17:0]	AD[10:0]
1,024 × 36	DI[35:0]	DO[35:0]	AD[9:0]
512 × 72	DI[71:0]	DO[71:0]	AD[8:0]

Table 4.3 shows the various attributes available for the Single-Port Memory (RAM\_DQ). You can select some of these attributes through the IP Catalog interface.

The ones without selectable options in IP Catalog are handled by the engine. However, you can access these options if you are working with the direct primitive instantiation.

**Table 4.3. Single-Port Memory Attributes in Lattice Avant Platform Devices** 

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port.	2- <max can="" device="" fit="" in="" that="" the=""></max>	512
Data Width	Data word width of the read and write port.	1–512	36
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Enable Output ClockEn	Clock Enable for the output clock This option requires enabling Output Register.	true, false	false
Enable Byte Enable	Allows you to select Byte Enable options.	true, false	false
Reset Assertion	Selection for the Reset to be synchronous or asynchronous to the Clock.	async, sync	sync
Memory Initialization	Allows you to initialize the memories to all 1s, 0s, or use a custom initialization by providing a memory file.	none, 0s, 1s, file	none
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	_	_

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

<sup>1.</sup> Address width is calculated from address depth.



Configuration Tab Attributes	Description	Values	Default Value
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for RAM\_DQ. The waveforms in Figure 4.3 and Figure 4.4 show the internal timing waveforms for the Single Port RAM (RAM\_DQ) without output registers and with output registers respectively.

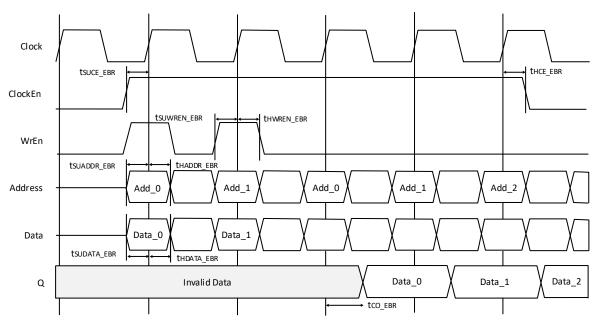


Figure 4.3. Single Port RAM Timing Waveform – without Output Registers

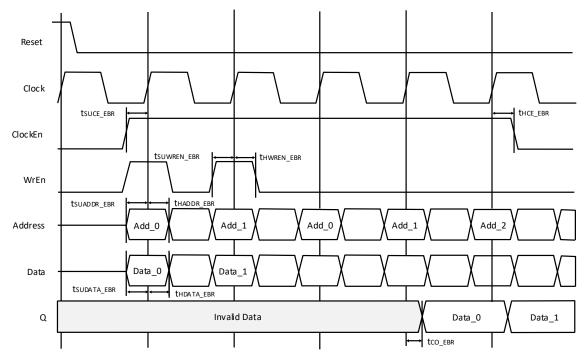


Figure 4.4. Single Port RAM Timing Waveform - with Output Registers



### 4.3. True Dual-Port RAM (RAM\_DP\_TRUE) – EBR-Based

The EBR blocks in Lattice Avant platform devices can be configured as True-Dual Port RAM or RAM\_DP\_TRUE. IP Catalog allows you to generate the Verilog-HDL or VHDL for the memory size as per design requirements.

IP Catalog generates the memory module, as shown in Figure 4.5.

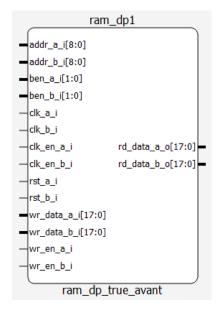


Figure 4.5. True Dual-Port Memory Module Generated by IP Catalog

Figure 4.6 provides the primitive that can be instantiated for the True Dual Port RAM. The primitive name is DP32K and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under cae library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 36 kb of memory. If the memory required is larger than 36 kb, then, cascading can be used, using the CS port (CSA[2:0] and CSB[2:0] in this case).

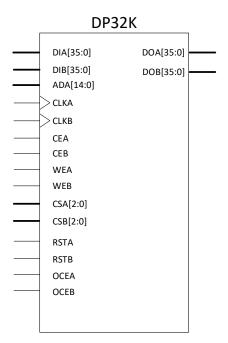


Figure 4.6. True Dual Port RAM Primitive for Lattice Avant Platform Devices

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



The various ports and definitions for True Dual-Port RAM are listed in Table 4.4. The table below lists the corresponding ports for the module generated by IP Catalog.

**Table 4.4. EBR-Based True Dual-Port Memory Port Definitions** 

Port Name	Direction	Width	Description
clk_a_i	Input	1	Clock for Port A
rst_a_i	Input	1	Reset for Port A
clk_en_a_i	Input	1	Clock Enable for Port A
wr_en_a_i	Input	1	Write Enable for Port A
wr_data_a_i	Input	Data Width	Data Input for Port A
addr_a_i	Input	Address Width	Address Bus for Port A
rd_data_a_o	Output	Data Width	Data Output for Port A
ben_a_i	Input	Byte Enable Width	Byte Enable for Port A
clk_b_i	Input	1	Clock for Port B
rst_b_i	Input	1	Reset for Port B
clk_en_b_i	Input	1	Clock Enable for Port B
wr_en_b_i	Input	1	Write Enable for Port B
wr_data_b_i	Input	Data Width	Data Input for Port B
addr_b_i	Input	Address Width	Address Bus for Port B
rd_data_b_o	Output	Data Width	Data Output for Port B
ben_b_i	Input	Byte Enable Width	Byte Enable for Port B

Each EBR block consists of 36,864 bits of RAM. The values for address (w and x) and data (y and z) of each EBR block are listed in Table 4.5.

Table 4.5. Dual Port Memory Sizes for 36 kb Memory for Avant Platform Devices

	able his built of the memory sizes for so his memory for Avant Fluction between						
Dual Port Memory Size	Input Data Port A	Input Data Port B	Output Data Port A	Output Data Port B	Address Port A	Address Port B	
32,768 × 1	DataInA	DataInB	QA	QB	AddressA(14:0)	AddressB(14:0)	
16,384× 2	DataInA(1:0)	DataInB(1:0)	QA(1:0)	QB(1:0)	AddressA(13:0)	AddressB(13:0)	
8,192 × 4	DataInA(3:0)	DataInB(3:0)	QA(3:0)	QB(3:0)	AddressA(12:0)	AddressB(12:0)	
4,096 × 9	DataInA(8:0)	DataInB(8:0)	QA(8:0)	QB(8:0)	AddressA(11:0)	AddressB(11:0)	
2,048 × 18	DataInA(17:0)	DataInB(17:0)	QA(17:0)	QB(17:0)	AddressA(10:0)	AddressB(10:0)	
1,024 × 36	DataInA(35:0)	DataInB(35:0)	QA(35:0)	QB(35:0)	AddressA(9:0)	AddressB(9:0)	

Table 4.6 shows the various attributes available for True Dual-Port Memory (RAM\_DP). You can select some of these attributes through the IP Catalog interface.

Table 4.6. True Dual-Port RAM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Port A Address Depth	Port A Address depth of the read and write port	2- <max can="" device="" fit="" in="" that="" the=""></max>	512
Port A Data Width	Port A Data word width of the read and write port	1–512	18
Port B Address Depth	Port B Address depth of the read and write port	2— <max can="" device="" fit="" in="" that="" the=""></max>	512
Port B Data Width	Port B Data word width of the Read and write port	1–512	18
Port A Enable Output Register	Port A Data Out port (QA) can be registered or not using this selection.	true, false	true
Port B Enable Output Register	Port B Data Out port (QB) can be registered or not using this selection.	true, false	true

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



Configuration Tab Attributes	Description	Values	Default Value
Byte Enable A	Allows you to select Byte Enable options.	true, false	false
Byte Enable B	Allows you to select Byte Enable options.	true, false	false
Reset Assertion A	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Assertion B	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Initialization	Allows you to initialize the memories to all 1s, 0s, or use a custom initialization by providing a memory file.	none, 0s, 1s, file	none
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	_	_
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for RAM\_DP\_TRUE. Waveforms in Figure 4.7 and Figure 4.8 show the internal timing waveforms for the True Dual Port RAM (RAM\_DP\_TRUE) without output registers and with output registers respectively.

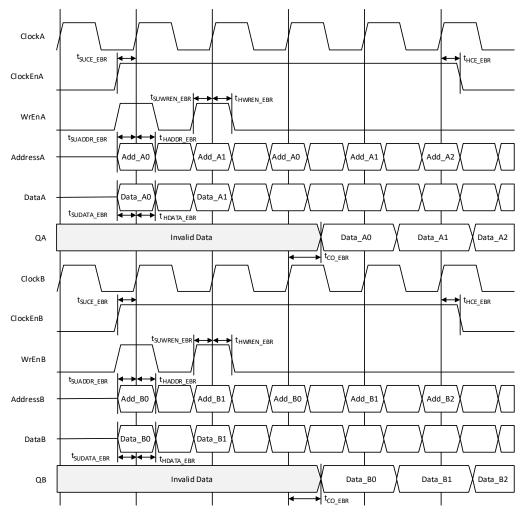


Figure 4.7. True Dual Port RAM Timing Waveform – without Output Registers



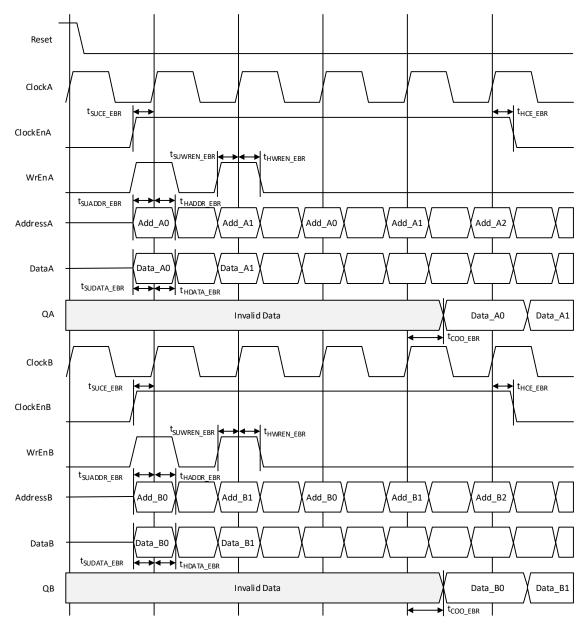


Figure 4.8. True Dual Port RAM Timing Waveform - with Output Registers



### 4.4. Pseudo Dual-Port RAM (RAM\_DP) – EBR-Based

FPGAs built on the Lattice Avant platform support all the features of Pseudo-Dual Port Memory Module or RAM\_DP. IP Catalog allows you to generate the Verilog-HDL or VHDL for the memory size as per design requirement.

IP Catalog generates the memory module, as shown in Figure 4.9.

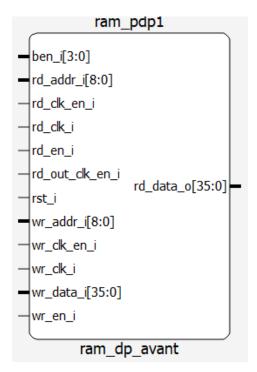


Figure 4.9. Pseudo Dual-Port Memory Module Generated by IP Catalog

Figure 4.10 shows the primitive that can be instantiated for the Pseudo-Dual Port RAM. The primitive name is PDP32K and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under cae library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 36 kb of memory. If the memory required is larger than 36 kb, then, cascading can be used, using the CS ports (CSW[2:0] and CSR[2:0] in this case).

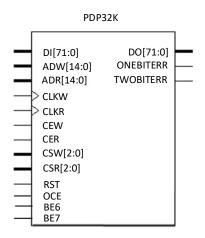


Figure 4.10. Pseudo-Dual Port RAM Primitive for Lattice Avant Platform Devices

The various ports and definitions for Pseudo Dual-Port memory are listed in Table 4.7. The table below lists the corresponding ports for the module generated by IP Catalog.



**Table 4.7. EBR-Based True Dual-Port Memory Port Definitions** 

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
wr_clk_en_i	Input	1	Write Clock Enable
rd_en_i	Input	1	Read Enable
rd_clk_en_i	Input	1	Read Clock Enable
rd_out_clk_en_i	Input	1	Read Output Register Clock Enable
wr_en_i	Input	1	Write Enable
ben_i	Input	Byte Enable Width	Byte Enable
wr_data_i	Input	Write Port Data Width	Write Data
wr_addr_i	Input	Write Port Address Width	Write Address
rd_addr_i	Input	Read Address Width	Read Address
rd_data_o	Output	Read Port Data Width	Read Data

Each EBR block consists of 36,864 bits of RAM. The values for address (w and x) and data (y and z) of each EBR block are listed in Table 4.8.

Table 4.8. Pseudo-Dual Port Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices

<b>Dual Port Memory Size</b>	Input Data Write Port	Output Data Read Port	Address Write Port	Address Read Port
32,768 × 1	Data	Q	WrAddress(14:0)	RdAddress(14:0)
16,384 × 2	Data(1:0)	Q(1:0)	WrAddress(13:0)	RdAddress(13:0)
8,192 × 4	Data(3:0)	Q(3:0)	WrAddress(12:0)	RdAddress(12:0)
4,096 × 9	Data(8:0)	Q(8:0)	WrAddress(11:0)	RdAddress(11:0)
2,048 × 18	Data(17:0)	Q(17:0)	WrAddress(10:0)	RdAddress(10:0)
1,024 × 36	Data(35:0)	Q(35:0)	WrAddress(9:0)	RdAddress(9:0)
512 × 72	Data(71:0)	Q(71:0)	WrAddress(8:0)	RdAddress(8:0)

Table 4.9 shows the various attributes available for the Pseudo Dual-Port Memory (RAM\_DP). You can select some of these attributes through the IP Catalog interface.

Table 4.9. Pseudo Dual-Port RAM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description		Default Value
Read Port Address Depth	Read Port Address depth of the read and write port	2–65536	512
Read Port Data Width	Read Port Data word width of the read and write port	1–256	36
Write Port Address Depth	Write Port Address depth of the read and write port	2–65536	512
Write Port Data Width	Write Port Data word width of the read and write port	1–256	36
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Enable Output ClockEn	Clock Enable for the output clock This option requires enabling Output Register.	true, false	false
Enable Byte Enable	Allows you to select Byte Enable options.	true, false	false
Enable ECC	This option allows you to enable error correction codes.	true, false	false
Reset Assertion	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize the memories to all 1s, 0s, or use a custom initialization by providing a memory file.	none, 0s, 1s, file	none

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



Configuration Tab Attributes	Description	Values	Default Value
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	-	_
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for Pseudo-Dual Port RAM (RAM\_DP). Waveforms in Figure 4.11 and Figure 4.12 show the internal timing waveforms for Pseudo-Dual Port RAM (RAM\_DP) without output registers and with output registers respectively.

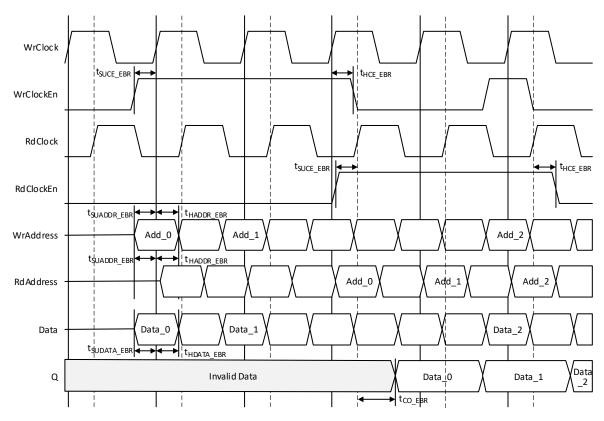


Figure 4.11. PSEUDO DUAL PORT RAM Timing Diagram – without Output Registers



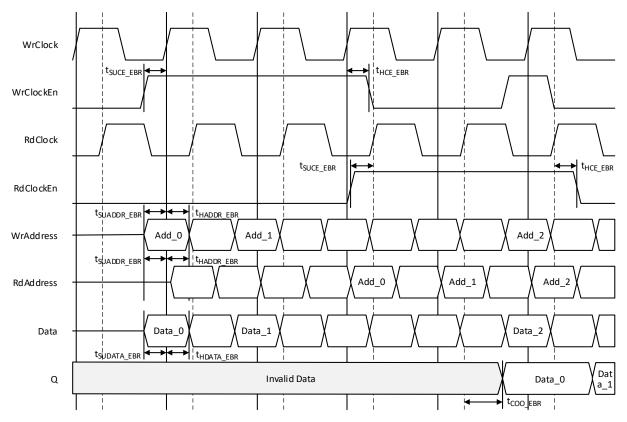


Figure 4.12. PSEUDO DUAL PORT RAM Timing Diagram - with Output Registers

### 4.5. Read Only Memory (ROM) - EBR-Based

FPGAs built on the Avant platform support all the features of the ROM Memory Module or ROM. IP Catalog allows you to generate the Verilog-HDL or VHDL for the memory size as per design requirement. You must provide the ROM memory content in the form of an initialization file.

IP Catalog generates the memory module, as shown in Figure 4.13.

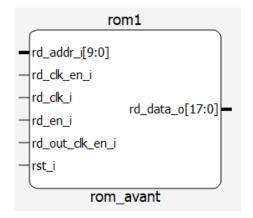


Figure 4.13. ROM - Read Only Memory Module Generated by IP Catalog

The various ports and definitions are listed in Table 4.10. The table below lists the corresponding ports for the module generated by IP Catalog and for the ROM primitive.

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



24

Table 4.10. EBR-Based ROM Port Definitions

Port Name	Direction	Width	Description
rd_clk_i	Input	1	Clock
rst_i	Input	1	Reset
rd_en_i	Input	1	Read Enable
rd_clk_en_i	Input	1	Input Clock Enable
rd_out_clk_en_i	Input	1	Output Clock Enable
rd_addr_i	Input	Address Width	Address Bus
rd_data_o	Input	Data Width	Data Output

When generating ROM using IP Catalog, you must provide the initialization file to pre-initialize the contents of the ROM. These files are the \*.mem files and they can be of binary or hex formats. The initialization files are discussed in detail in the Initializing Memory section.

Each EBR block consists of 36,864 bits of RAM. The values for xs (for address) and ys (data) for each EBR block for the devices are included in Table 4.11.

Table 4.11. ROM Memory Sizes for 36 kb Memory for Lattice Avant Platform Devices

Dual Port Memory Size	Output Data Read Port	Address Read Port
32,768 × 1	Q	RdAddress(14:0)
16,384 × 2	Q(1:0)	RdAddress(13:0)
8,192 × 4	Q(3:0)	RdAddress(12:0)
4,096 × 9	Q(8:0)	RdAddress(11:0)
2,049 × 18	Q(17:0)	RdAddress(10:0)
1,024 × 36	Q(35:0)	RdAddress(9:0)
512 × 72	Q(71:0)	RdAddress(8:0)

Table 4.12 shows the various attributes available for the Read Only Memory (ROM). You can select some of these attributes through the IP Catalog interface.

Table 4.12. ROM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2–65536	512
Data Width	Data word width of the read and write port	1–512	36
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Enable Output Clock	Enables read output clock.	true, false	false
Reset Assertion Mode	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Initialization	Allows you to initialize the memories to all 1s, 0s, or use a custom initialization by providing a memory file.	0s, 1s, file	Os
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	_	_
Memory File Format This option allows you to select if the memory file is formatted as binary or hex.		binary, hex	hex

You have the option to enable the output registers for Read Only Memory (ROM). Figure 4.14 and Figure 4.15 show the internal timing waveforms for ROM without output registers and with output registers respectively.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice. FPGA-TN-02289-0.82



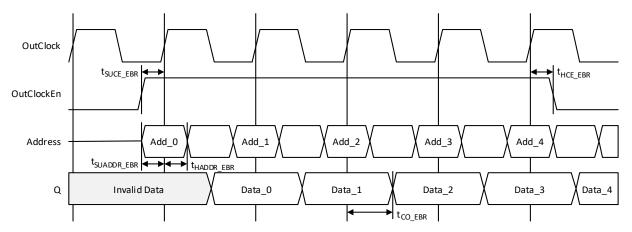


Figure 4.14. ROM Timing Waveform – without Output Registers

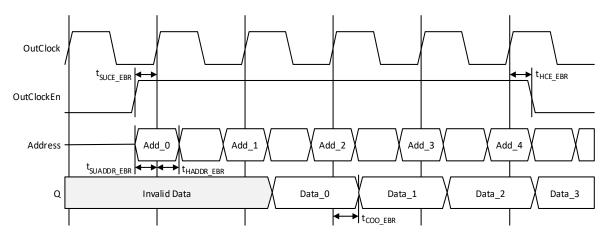


Figure 4.15. ROM Timing Waveform - with Output Registers



# 5. First In First Out (FIFO) Memory

Lattice Avant platform devices support two different types of FIFOs:

- Single-Clock FIFO (FIFO)
- Dual-Clock FIFO (FIFO DC)

The EBR blocks in Lattice Avant platform devices can be configured as LUT-based or EBR-based, as well as Single-Clock First In First Out Memory (FIFO\_DC). IP Catalog allows you to generate the Verilog-HDL or VHDL netlist for various memory sizes depending on design requirements.

IP Catalog generated FIFO modules and the operation are discussed in detail in the following section.

### 5.1. Single-Clock FIFO (FIFO) – EBR-Based or LUT-Based

Figure 5.1 shows the module that is generated by the IP Catalog for FIFO.

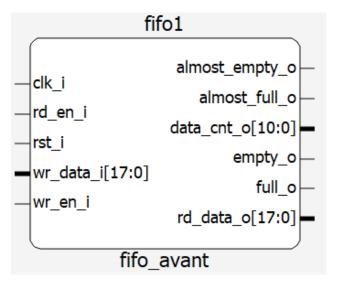


Figure 5.1. FIFO Module Generated by IP Catalog

The various ports and definitions for the FIFO are listed in Table 5.1.

Table 5.1. Port Names and Definitions for FIFO

Port Name	Direction	Width	Description
clk_i	Input	1	Write Clock
rst_i	Input	1	Reset
wr_en_i	Input	1	Write Enable
rd_en_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
rd_data_o	Output	Data Width	Read Data
full_o	Output	1	Full Flag
empty_o	Output	1	Empty Flag
almost_full_o	Output	1	Almost Full Flag
almost_empty_o	Output	1	Almost Empty Flag
data_cnt_o	Output	Address Width	Data Counter Width based on MEM Address Width

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



**Table 5.2. FIFO Attributes for Lattice Avant Platform Devices** 

Configuration Tab Attributes	Description		Default Value	
Implementation Type	EBR-based or LUT-based	EBR, LUT	EBR	
Address Depth	Address depth of the read and write port Values are powers of two.	2- <max that<br="">can fit in the device&gt;</max>	1024	
Controller Implementation	FIFO Controller Implementation Option  To enable the implementation type as LUT-based, or enable the Data Count output, you need to select LUT.	LUT, HW	HW	
Enable FWFT	Enables the First Word Fall Through mode. This is only available in HW mode.	true, false	false	
Data Width	Data word width of the read and write port	1–256	18	
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true	
Reset Assertion	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync	
Enable Almost Empty Flag	Enables the generation of Almost Empty Flag.	true, false	true	
Almost Empty Assertion Type	This option allows you to select the type of threshold to be used for the Almost Empty Flag. Static threshold is set by constant parameter while Dynamic threshold is set though the input ports. Single threshold provides only the assertion level while Dual threshold provides both assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Dual	
Almost Empty Assert Level	This option allows you to set the assertion level of Almost Empty Flag. This is applicable for Static-(Single/Dual) threshold mode.	1–Address Depth	1	
Almost Empty De-assert Level	This option allows you to set the de-assertion level of Almost Empty Flag after it goes high. This is applicable only for Static-Dual threshold mode.	1–Address Depth	2	
Enable Almost Full Flag	Enables the generation of Almost Full Flag.	true, false	true	
Almost Full Assertion Type	This option allows you to select the type of threshold to be used for Almost Full Flag. Static threshold is set by constant parameter while Dynamic threshold is set though the input ports.  Single threshold provides only the assertion level while Dual threshold provides both assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Dual	
Almost Full Assert Level	This option allows you to set the assertion level of Almost Full Flag. Applicable for Static-(Single/Dual) threshold mode.	1–Address Depth	1023	
Almost Full De-assert Level	This option allows you to set the de-assertion level of Almost Full Flag after it goes high. This option is applicable only for Static-Dual threshold mode.	1–Address Depth	1022	
Enable Data Count	This option allows you to enable generation of write data count.	true, false	false	



Let us first discuss the non-pipelined or the FIFO without output registers. Figure 5.2 shows the operation of the FIFO when it is empty and the data begins to be written into the FIFO.

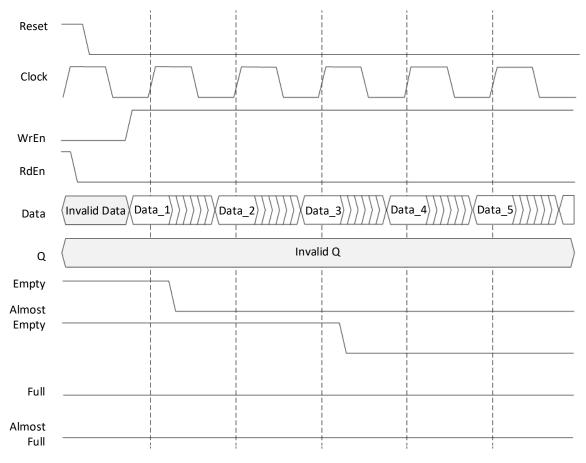


Figure 5.2. FIFO Without Output Registers - Start of Data Write Cycle

The WrEn signal must be high to start writing to the FIFO. The Empty and Almost Empty flags are high to begin and Full and Almost Full are low.

When the first data is written to the FIFO, the Empty flag de-asserts or goes low since the FIFO is no longer empty. In this figure, it is assumed that the Almost Empty flag setting is 3 (address location 3). As such, the Almost Empty flag is de-asserted when the third address location is filled.



Assume that you continue to write into the FIFO to fill it. When the FIFO is filled, the Almost Full and Full flags are asserted. Figure 5.3 shows the behavior of these flags. In this figure, it is assumed that the FIFO depth is N.

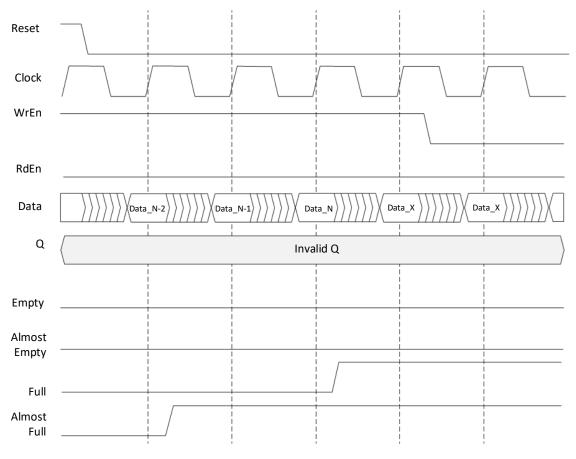


Figure 5.3. FIFO Without Output Registers - End of Data Write Cycle

In Figure 5.3, the Almost Full flag is two locations before the FIFO is filled. The Almost Full flag is asserted when the N-2 location is written, and the Full flag is asserted when the last word is written into the FIFO.

Data\_X data inputs are not written because the FIFO is full, with the Full flag being high.



Examine the waveforms when the contents of the FIFO are read out. Figure 5.4 shows the start of the read cycle. The RdEn signal goes high and the data read starts. The Full and Almost Full flags are de-asserted.

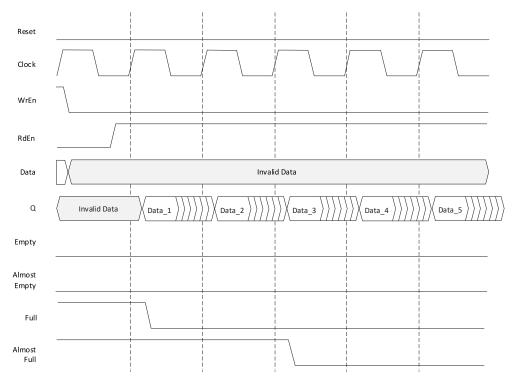


Figure 5.4. FIFO Without Output Registers - Start of Data Read Cycle

Similarly, as the data is read out and FIFO is emptied, the Almost Empty and Empty flags are asserted (Figure 5.5).

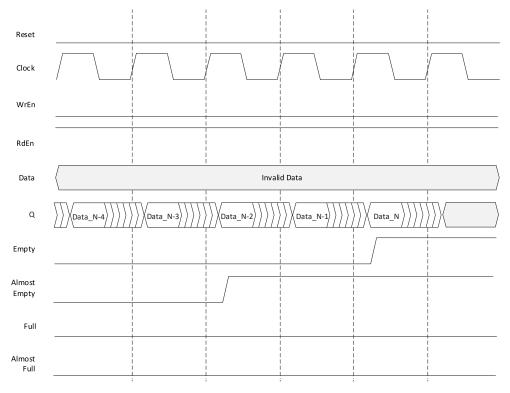


Figure 5.5. FIFO Without Output Registers - End of Data Read Cycle

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice. 30



Figure 5.2 to Figure 5.5 show the behavior of non-pipelined FIFO or FIFO without output registers. When the registers are pipelined, the output data is delayed by one clock cycle. There is also an option for output registers to be enabled by the RdEn signal.

Figure 5.6 to Figure 5.9 show similar waveforms for the FIFO with output registers and Figure 5.10 shows a FIFO with output registers enable with RdEn. Note that flags are asserted and de-asserted with similar timing to the FIFO without output registers. Only the data out Q is delayed by one clock cycle.

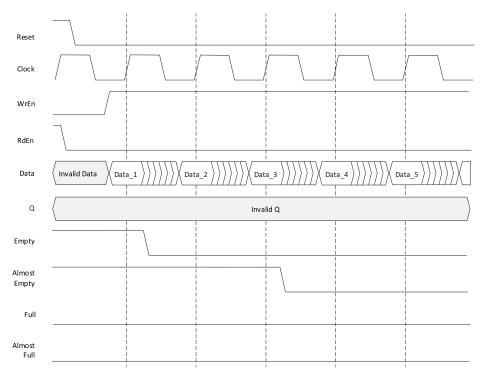


Figure 5.6. FIFO with Output Registers – Start of Data Write Cycle

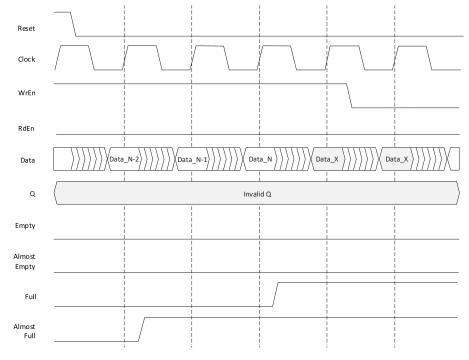


Figure 5.7. FIFO with Output Registers - End of Data Write Cycle

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



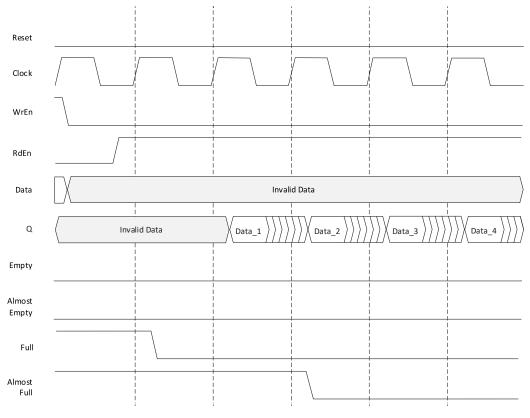


Figure 5.8. FIFO with Output Registers – Start of Data Read Cycle

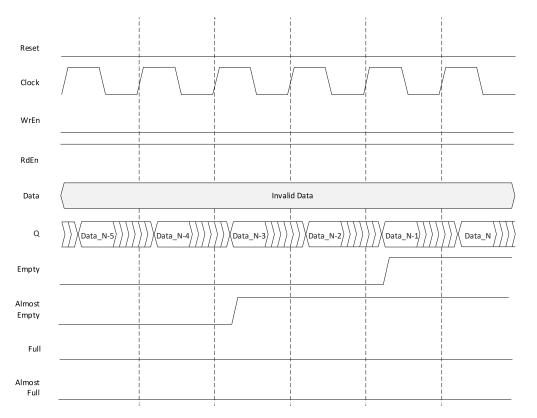


Figure 5.9. FIFO with Output Registers – End of Data Read Cycle

© 2024 Lattice Semiconductor Corp. All Lattice trademarks, registered trademarks, patents, and disclaimers are as listed at www.latticesemi.com/legal.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.



If the option enable output register with RdEn is selected, it still delays the data out by one clock cycle, as compared to the non-pipelined FIFO. The RdEn must also be high during that clock cycle. Otherwise, the data takes an extra clock cycle when the RdEn signal goes true.

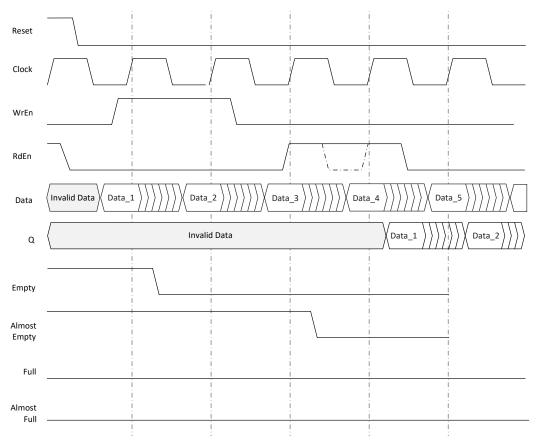


Figure 5.10. FIFO with Output Registers and RdEn on Output Registers



# Dual-Clock First-In-First-Out (FIFO\_DC) – EBR-Based or LUT-Based

Figure 6.1 shows the module that is generated by the IP Catalog for FIFO.

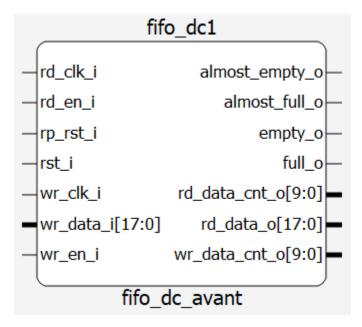


Figure 6.1. FIFO\_DC Module Generated by IP Catalog

The various ports and definitions for the FIFO\_DC are listed in Table 6.1. The software attributes are listed in Table 6.2.

Table 6.1. Port Names and Definitions for FIFO\_DC

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
rp_rst_i	Input	1	Read Pointer Reset
wr_en_i	Input	1	Write Enable
rd_en_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
rd_data_o	Output	Data Width	Read Data
full_o	Output	1	Full Flag
empty_o	Output	1	Empty Flag
almost_full_o	Output	1	Almost Full Flag
almost_empty_o	Output	1	Almost Empty Flag
wr_data_cnt_o	Output	Address Width	Write Data Counter
rd_data_cnt_o	Output	Address Width	Read Data Counter



Table 6.2. FIFO\_DC Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Write Address Depth	Address depth of the write port Values are powers of two.	2- <max can="" device="" fit="" in="" that="" the=""></max>	512
Write Data Width	Data word width write port	1–256	18
Read Address Depth	Address depth of the read port.  Note: If not equal to Write Address Depth, the valid values are powers of two such that the ratio between Write and Read data widths are also powers of two.	2— <max can="" device="" fit="" in="" that="" the=""></max>	512
Read Data Width	Data word width read port	1–256	18
Controller Implementation	FIFO Controller Implementation Option To enable the implementation type as LUT-based, or enable the Data Count output, you need to select LUT.	LUT, HW	HW
Enable FWFT	Enables the First Word Fall Through mode. This is only available in HW mode.	true, false	false
Implementation Type	EBR-based or LUT-based	EBR, LUT	EBR
Enable Output Register	Data Out port (rd_data_o) can be registered or not using this selection.	true, false	false
Reset Mode	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Enable Almost Empty Flag	Enables the generation of Almost Empty Flag.	true, false	true
Almost Empty Assertion Type	This option allows you to select the type of threshold to be used for Almost Empty Flag. Static threshold is set by constant parameter while Dynamic threshold is set though the input ports. Single threshold provides only the assertion level while Dual threshold provides both assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Dual
Almost Empty Assert Level	This option allows you to set the assertion level of Almost Empty Flag. This is applicable for Static-(Single/Dual) threshold mode.	1–Address Depth	1
Almost Empty De-assert Level	This option allows you to set the de-assertion level of Almost Empty Flag after it goes high. This is applicable only for Static-Dual threshold mode.	1–Address Depth	2
Enable Almost Full Flag	Enables the generation of Almost Full Flag.	true, false	false
Almost Full Assertion Type  This option allows you to select the type of threshold to be used for Almost Full Flag. Static threshold is set by constant parameter while Dynamic threshold is set though the input ports. Single threshold provides only the assertion level while Dual threshold provides both assertion and de-assertion level.		Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Dual
Almost Full Assert Level	This option allows you to set the assertion level of Almost Full Flag. This is applicable for Static-(Single/Dual) threshold mode.	1–Address Depth	511
Almost Full De-assert Level	This option allows you to set the de-assertion level of Almost Full Flag after it goes high. This is applicable only for Static-Dual threshold mode.	1–Address Depth	510
Enable Data Count (Synchronized to Write clock)	This options allows you to enable generation of write data count.	true, false	false
Enable Data Count (Synchronized to Read clock)	This options allows you to enable generation of read data count.	true, false	false



### 6.1. FIFO\_DC Flags

As a hardware FIFO, FIFO\_DC avoids latency to the flags during assertion or de-assertion, which distinguishes it from devices with emulated FIFO.

Figure 6.2 and Figure 6.3 show waveforms for FIFO\_DC without output registers. Figure 6.2 shows the operation of the FIFO DC when it is empty and the data begins to be written into the FIFO.

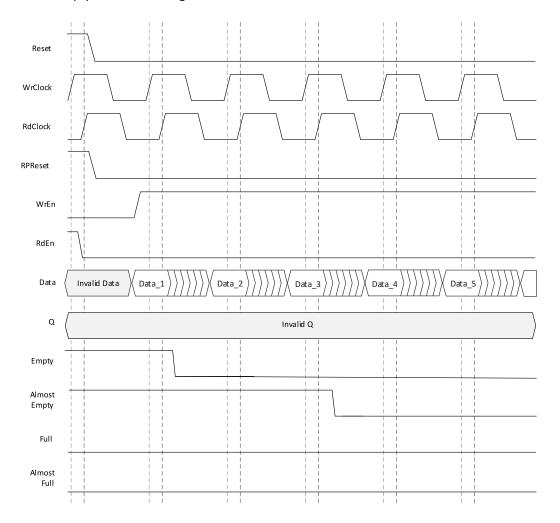


Figure 6.2. FIFO\_DC Without Output Registers - Start of Data Write Cycle

The WrEn signal has to be high to start writing into the FIFO\_DC. The Empty and Almost Empty flags are high to begin and Full and Almost Full are low.

When the first data is written into the FIFO\_DC, the Empty flag de-asserts or goes low, as the FIFO\_DC is no longer empty. In this figure, it is assumed that the Almost Empty setting flag setting is 3 (address location 3). The Almost Empty flag is de-asserted when the third address location is filled.

Assume that you continue to write into the FIFO\_DC to fill it. When the FIFO\_DC is filled, the Almost Full and Full Flags are asserted. Figure 6.3 shows the behavior of these flags. In this figure, it is assumed that FIFO\_DC depth is N.



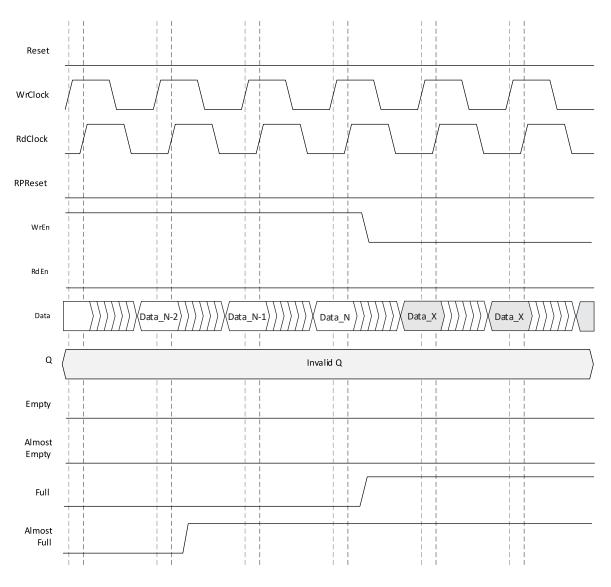


Figure 6.3. FIFO\_DC Without Output Registers – End of Data Write Cycle

In Figure 6.3, the Almost Full flag is two locations before the FIFO\_DC is filled. The Almost Full flag is asserted when the N-2 location is written, and the Full flag is asserted when the last word is written into the FIFO\_DC.

Data\_X data inputs are not written because the FIFO\_DC is full, with the Full flag being high.

Note that the assertion of these flags is immediate and there is no latency when they go true.



Examine the waveforms when the contents of the FIFO\_DC are read out. Figure 6.4 shows the start of the read cycle. RdEn goes high and the data read starts. The Full and Almost Full flags are de-asserted, as shown in Figure 6.4.

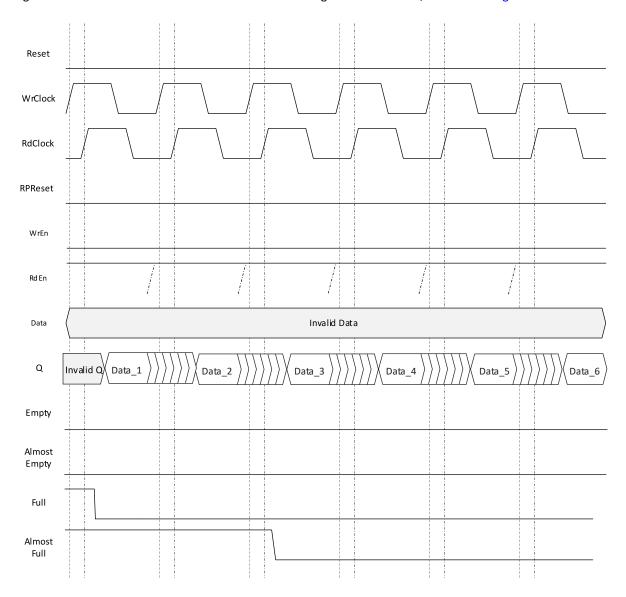


Figure 6.4. FIFO\_DC Without Output Registers – Start of Data Read Cycle

Similarly, as the data is read out and FIFO\_DC is emptied, the Almost Empty and Empty flags are asserted (Figure 6.5).



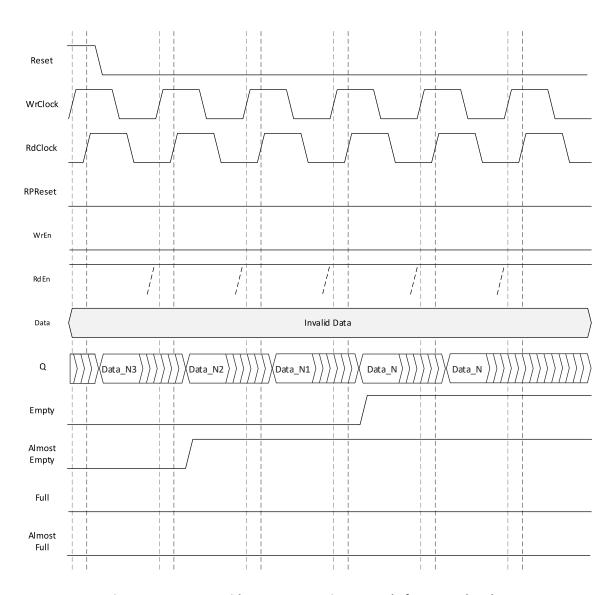


Figure 6.5. FIFO\_DC Without Output Registers – End of Data Read Cycle



Figure 6.2 to Figure 6.5 show the behavior of the non-pipelined FIFO\_DC or FIFO\_DC without output registers. When you pipeline the registers, the output data is delayed by one clock cycle. There is an extra option for output registers to be enabled by the RdEn signal.

Figure 6.6 to Figure 6.9 show similar waveforms for FIFO\_DC with output registers and Figure 6.10 shows FIFO\_DC with output registers enable by RdEn. Note that flags are asserted and de-asserted with timing similar to the FIFO\_DC without output registers. However, only the data out Q is delayed by one clock cycle.

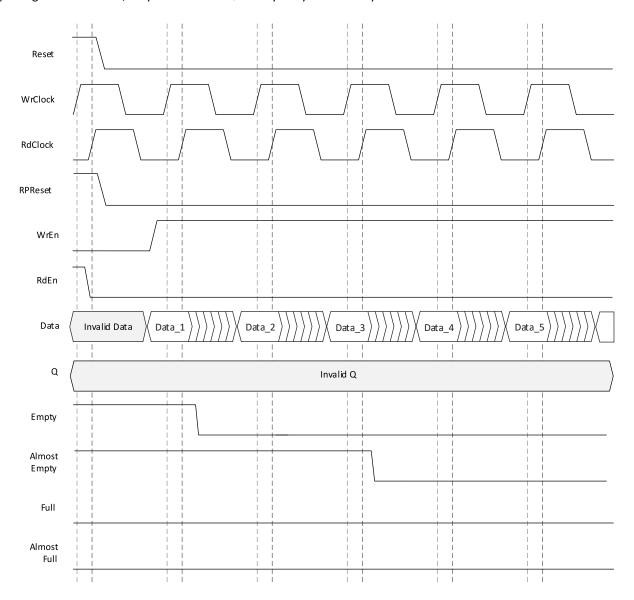


Figure 6.6. FIFO\_DC with Output Registers – Start of Data Write Cycle



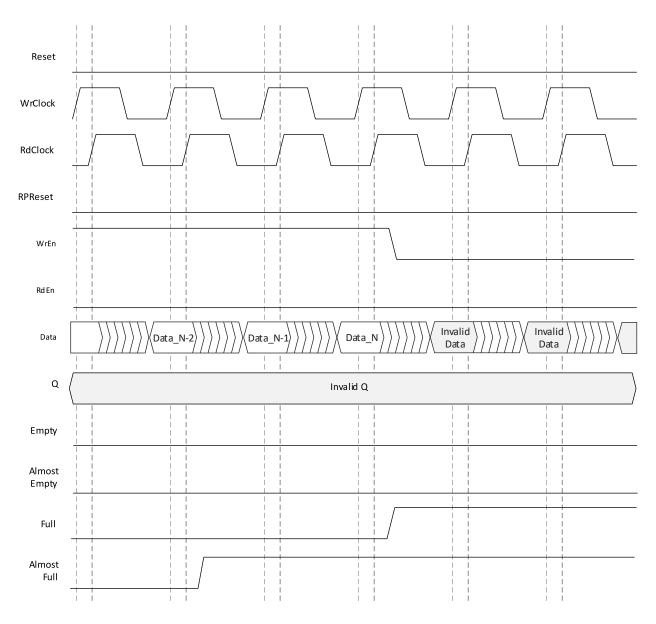


Figure 6.7. FIFO\_DC with Output Registers - End of Data Write Cycle



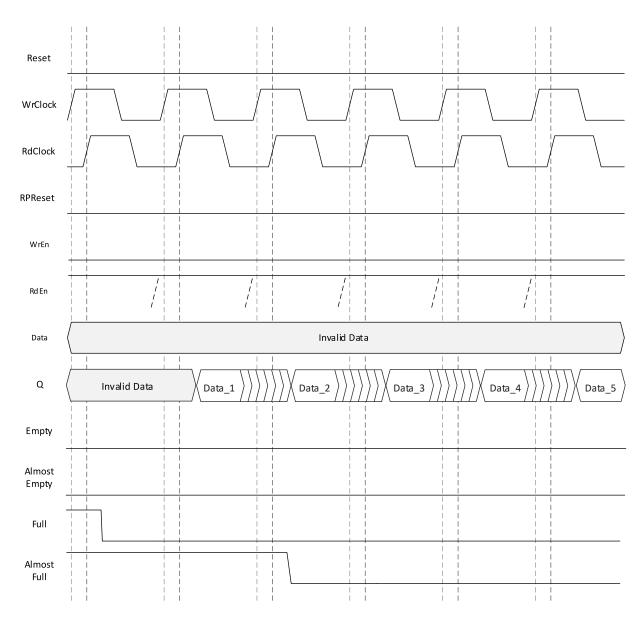


Figure 6.8. FIFO\_DC with Output Registers – Start of Data Read Cycle



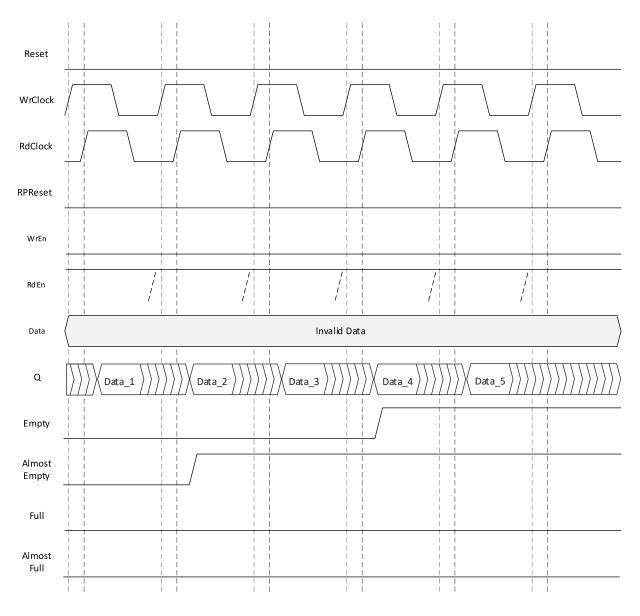


Figure 6.9. FIFO\_DC with Output Registers – End of Data Read Cycle



If you select the option to enable output register with RdEn, data out is still delayed by one clock cycle, as compared to the non-pipelined FIFO\_DC. The RdEn signal must be high during that clock cycle. Otherwise, the data takes an extra clock cycle when the RdEn signal goes true.

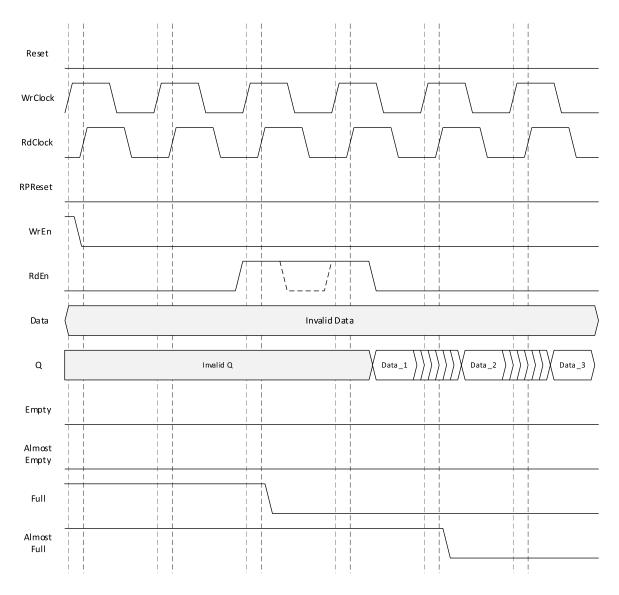


Figure 6.10. FIFO\_DC with Output Registers and RdEn on Output Registers

When using FIFO\_DC with different data widths on read and write ports, make sure that the wider data width is the multiple of the smaller one. In addition to that, the words written or read out must follow the same relationship. For example, assume that the Dataln (write port) width is 8-bits and the DataOut (read port) is 16-bits. In this case, there is a factor of 2 between the two. For every two words written in the FIFO\_DC, one word is read out. If you write an odd number of words, such as seven for example, then the read port reads three complete words, and one half word. The other half of the incomplete word is either the all zeroes (0s) or prior data written at the 8th location.

If you reverse the number of bits on Dataln and DataOut, then for every written word, two words are read out. To completely read the FIFO\_DC, you need twice the number of clock cycles on the write port.

FIFO\_DC does not include any arbitration logic, it has to be implemented outside of the FIFO\_DC. Read and Write Count pointers can be used to aid in counting the number of written or read words.



## Distributed Single-Port RAM (Distributed\_SPRAM) – PFU-Based

PFU-based Distributed Single-Port RAM is created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 7.1 shows the Distributed Single-Port RAM module generated by IP Catalog.

```
dist_ram1

addr_i[4:0]
-clk_en_i
-clk_i
-rst_i
wr_data_i[7:0]
-wr_en_i

distributed_spram
```

Figure 7.1. Distributed Single-Port RAM Module Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic such as a clock or reset is generated by utilizing the resources available in the PFU.

Ports such as Read Clock (RdClock) and Read Clock Enable (RdClockEn) are not available in the hardware primitive. These are generated by IP Catalog when you want to enable the output registers in the IP Catalog configuration.

Figure 7.2 provides the primitive that can be instantiated for the Single Port Distributed RAM. The primitive name is SPR16X4A and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under cae\_library/synthesis folder in the Lattice Radiant software installation folder.

It is to be noted that every three slices can accommodate 64 bits of memory. If the memory required is larger than 64 bits, then, cascading can be used. Furthermore, the ports can be registered using external PFU registers.

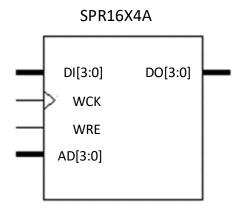


Figure 7.2. Single Port Distributed RAM Primitive for Lattice Avant Platform Devices

The various ports and definitions listed in Table 7.1. The table below lists the corresponding ports for the module generated by IP Catalog and for the primitive.

FPGA-TN-02289-0-82



Table 7.1. PFU-Based Distributed Single Port RAM Port Definitions

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	Clock Enable
we_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
addr_i	Input	Address Width	Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed SPRAM are included in Table 7.2.

Table 7.2. Distributed\_SPRAM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes  Description		Values	Default Value
Address Depth Address depth of the read and write port		2- <max that<br="">can fit in the device&gt;</max>	32
Data Width	Data word width of the read and write port	1–256	8
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Reset Mode	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize the memories to all 1s, 0s, or use a custom initialization by providing a memory file.	none, 0s, 1s, memory file	none
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	1	_
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

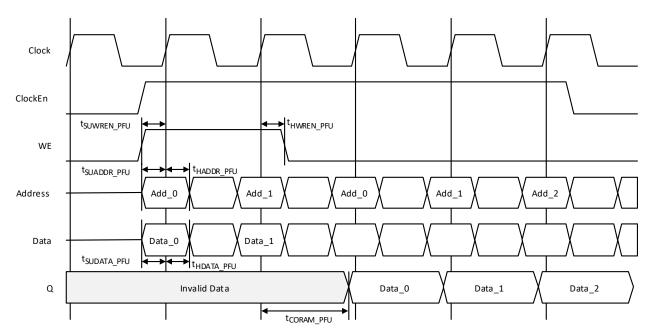


Figure 7.3. PFU-Based Distributed Single Port RAM Timing Waveform - without Output Registers



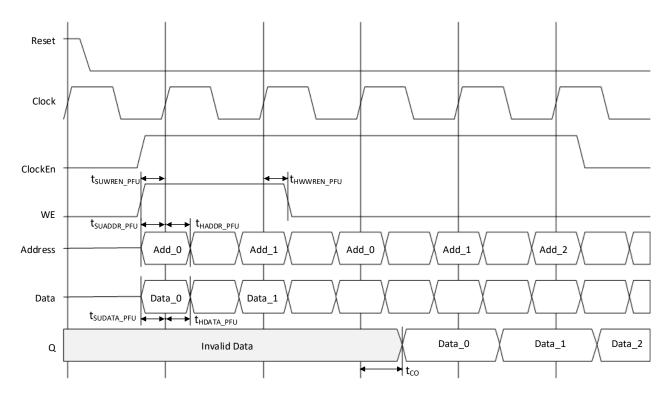


Figure 7.4. PFU-Based Distributed Single Port RAM Timing Waveform – with Output Registers



## 8. Distributed Dual-Port RAM (Distributed DPRAM) - PFU-Based

PFU-based Distributed Dual-Port RAM is also created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 8.1 shows the Distributed Single-Port RAM module as generated by IP Catalog.

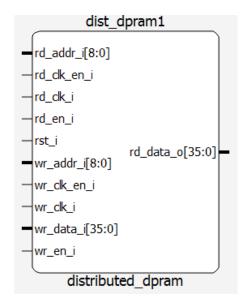


Figure 8.1. Distributed Dual-Port RAM Module Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic such as a clock or reset is generated by utilizing the resources available in the PFU.

Ports such as the Read Clock and Read Clock Enable are not available in the hardware primitive. These are generated by IP Catalog when you want to enable the output registers in the IP Catalog configuration.

Figure 8.2 provides the primitive that can be instantiated for the Dual Port Distributed RAM. The primitive name is DPR16X4A and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under cae\_library/synthesis folder in the Lattice Radiant software installation folder.

It is to be noted that every three slices can accommodate 64 bits of memory. If the memory required is larger than 64 bits, then, cascading can be used. Furthermore, the ports can be registered using external PFU registers.

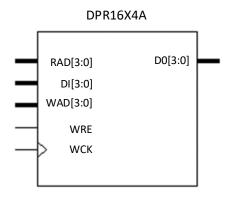


Figure 8.2. Dual Port Distributed RAM Primitive for Lattice Avant Platform Devices

The various ports and the definitions are listed in Table 8.1. The table lists the corresponding ports for the module generated by IP Catalog and for the primitive.

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice.

FPGA-TN-02289-0.82



Table 8.1. PFU-Based Distributed Dual-Port RAM Port Definitions

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
wr_clk_en_i	Input	1	Write Clock Enable
rd_clk_en_i	Input	1	Read Clock Enable
rd_en_i	Input	1	Read Enable
wr_en_i	Input	1	Write Enable
wr_data_i	Input	Data Width	Write Data
wr_addr_i	Input	Address Width	Read Address
rd_addr_i	Input	Address Width	Read Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed DPRAM are described in Table 8.2.

Table 8.2. Distributed\_DPRAM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2- <max can="" device="" fit="" in="" that="" the=""></max>	512
Data Width	Data word width of the read and write port	1–256	36
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Reset Mode	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	This option allows you to initialize memories to all 1s, 0s, or use a custom initialization by providing a memory file.	none, 0s, 1s, memory file	none
Memory File	When a memory file is selected, you can browse to the memory file for custom initialization of RAM.	_	_
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

You have the option of enabling the output registers for Distributed Dual Port RAM (Distributed\_DPRAM). Figure 8.3 and Figure 8.4 show the internal timing waveforms for the Distributed Dual Port RAM (Distributed\_DPRAM) without and with output registers repsectively.



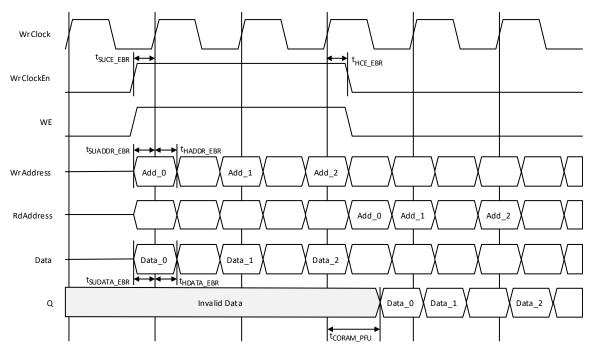


Figure 8.3. PFU-Based Distributed Dual Port RAM Timing Waveform - without Output Registers

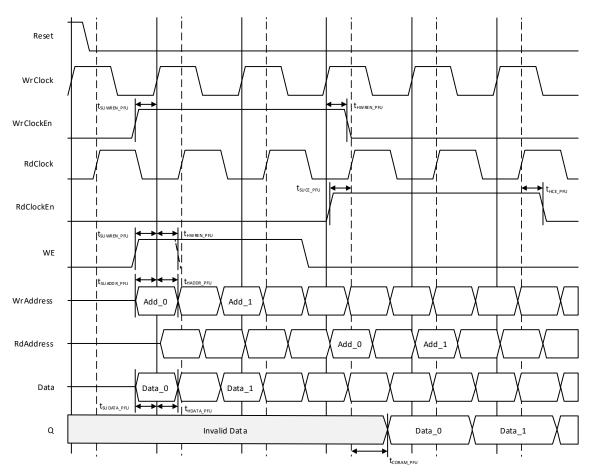


Figure 8.4. PFU-Based Distributed Dual Port RAM Timing Waveform - with Output Registers



51

## 9. Distributed ROM (Distributed ROM) - PFU-Based

PFU-based Distributed ROM is also created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 9.1 shows the Distributed ROM module generated by IP Catalog.

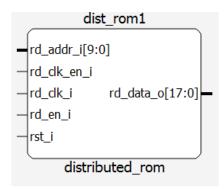


Figure 9.1. Distributed ROM Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic such as a clock or reset is generated by utilizing the resources available in the PFU.

Ports such as Out Clock and Out Clock Enable are not available in the hardware primitive. These are generated by IP Catalog when you want to enable the output registers in the IP Catalog configuration.

If the memory required is larger than what can fit in the primitive bits, then, cascading can be used. Furthermore, the ports can be registered by using external PFU registers.

The various ports and the definitions are listed in Table 9.1. The table below lists the corresponding ports for the module generated by IP Catalog and for the primitive.

Table 9.1. PFU-Based Distributed ROM Port Definitions

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	Clock Enable
addr_i	Input	Address Width	Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed ROM are included in Table 9.2.

Table 9.2. Distributed\_ROM Attributes for Lattice Avant Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	dress Depth Address depth of the read and write port		1024
Data Width	Data word width of the read and write port	1–256	18
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	true, false	true
Reset Mode	Selection for the Reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory File When a memory file is selected, you can browse to the me file for custom initialization of RAM.		_	_
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex

All other brand or product names are trademarks or registered trademarks of their respective holders. The specifications and information herein are subject to change without notice. FPGA-TN-02289-0.82



You have the option to enable the output registers for Distributed ROM (Distributed\_ROM). Figure 9.2 and Figure 9.3 show the internal timing waveforms for the Distributed ROM without and with output registers respectively.

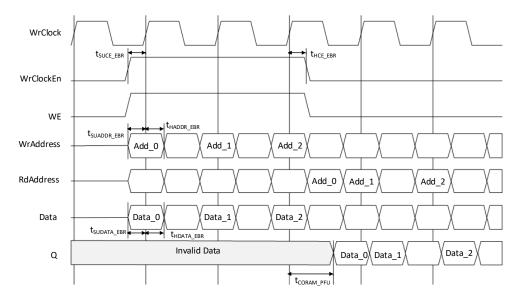


Figure 9.2. PFU-Based Distributed Dual Port RAM Timing Waveform – without Output Registers

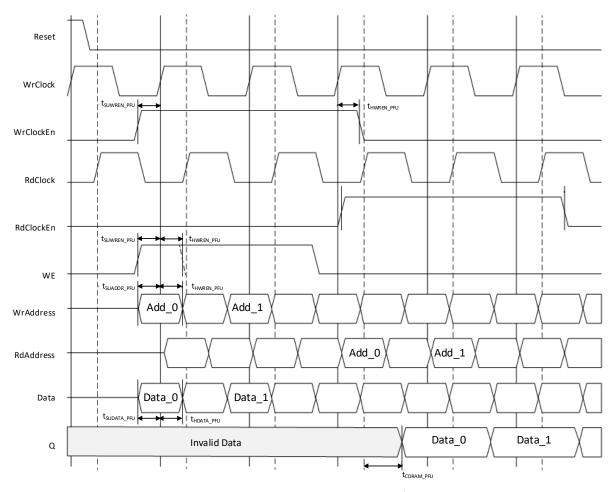


Figure 9.3. PFU-Based Distributed Dual Port RAM Timing Waveform - with Output Registers



## 10. Initializing Memory

In each memory mode, it is possible to specify the power-on state of each bit in the memory array. This allows the memory to be used as ROM if desired. Each bit in the memory array can have a value of 0 or 1.

### 10.1. Initialization File Formats

The initialization file is an ASCII file, which the designer can create or edit using any ASCII editor. IP Catalog supports two memory file formats:

- Binary file
- Hex file

The file name for the memory initialization file is \*.mem (<file\_name>.mem). Each row includes the value to be stored in a particular memory location. The number of characters or the number of columns represent the number of bits for each address or the width of the memory module respectively.

The memory initialization can be static or dynamic. In case of static initialization, the memory values are stored in the bitstream. Dynamic initialization of memories, involve memory values stored in the external flash and can be updated by user logic knowing the EBR address locations. The size of the bitstream (bit or rbt file) is larger due to static values stored in them.

The initialization file is primarily used for configuring the ROMs. RAMs can also use the initialization file to preload memory contents.

#### 10.1.1. Binary File

The binary file is a text file of 0s and 1s. The rows indicate the number of words and the columns indicate the width of the memory.

### Memory Size 20×32

Memory Size 20×32
0010000010000001000001000000
0000001000000100000001
00000010000001000000010
000000110000001100000011
00000100000010000001000000100
000001010000010100000101
000001100000011000000110
000001110000011100000111
0000100001001000000100010000
0000100101001001001001001001
0000101001001001001001001001010
00001011010010110000101101001011
000011000000110000001100
00001101001011010000110100101101
000011100011111000001111110
00001111001111110000111110111111
00010000001000000100000010000
0001000100010001000100010001
000100100001001000010010010
000100110001001100010011



### 10.1.2. Hex File

The hex file is a text file of hexadecimal characters arranged in a similar row-column arrangement. The number of rows in the file is the same as the number of address locations, with each row indicating the content of the memory location.

# Memory Size 8×16 A001 0B03 1004 CE06 0007 040A 0017



## References

For more information, refer to:

- Avant-E web Page
- Avant-G web Page
- Avant-X web Page
- Lattice Avant Platform web page
- IP Cores and Reference Designs for Avant Devices
- Kits, Boards, and Demonstrations for Avant Devices
- Lattice Insights for Lattice Semiconductor training courses and learning plans



## **Technical Support Assistance**

Submit a technical support case through www.latticesemi.com/techsupport. For frequently asked questions, refer to the Lattice Answer Database at https://www.latticesemi.com/Support/AnswerDatabase.



# **Revision History**

### Revision 0.82, September 2024

Section	Change Summary
Disclaimers	Updated this section.
Inclusive Language	Added this section.
Memory Modules	Updated Figure 4.3. Single Port RAM Timing Waveform – without Output Registers to add the previously missing waveform for <i>WrEn</i> .
References	Added this section.

### Revision 0.81, December 2022

Section	Change Summary	
All	Minor adjustments in formatting across the document.	
Memory Generation	Updated Utilizing PMI section content to change memory size to 1 kb and change attribute to syn_ramstyle and syn_romstyle.	
Memory Features	<ul> <li>Updated ECC in Memory Modules section to add 8-bit ECC code.</li> <li>Updated Byte Enable section to add info that byte-enable is only available if data width is greater than 9 bits.</li> </ul>	
Memory Modules	<ul> <li>Updated Reset section to add GSR signal information.</li> <li>Updated Figure 4.2. Single Port RAM Primitive for Avant Platform Devices and Figure 4.6. True Dual Port RAM Primitive for Avant Platform Devices to add OCE and OCEA/OCEB pins respectively.</li> </ul>	

## Revision 0.80, April 2022

Section	Change Summary
All	First preliminary release.



www.latticesemi.com